

PRODUCTION DATA SHEET

DESCRIPTION

cost external components.

bandwidth error amplifier and internal quiescent current. compensation. Tight output voltage The LX1736 operational supply voltage regulation tolerance for all line, load shutdown during fault conditions. external resistors

The LX1736 operates as a Current The regulator is capable of providing an Mode PWM Buck regulator that output load current up to 1.25A and has switches to PFM mode under light no minimum load current requirement loads. The entire regulator function is for stable operation. Current limit implemented with only a few, low- senses on a cycle-by cycle basis to protect the switch. Power conversion The LX1736 responds quickly to efficiency is maximized with PFM dynamic load changes using a high mode of operation and low regulator

regulation is maintained with the range covers 4.0V to 6.0V, features temperature compensated 800mV, include: power on delay; soft start to bandgap reference achieving +/-3.5% limit inrush currents and thermal

and thermal conditions. The output The 6-pin JEDEC MO-229 package voltage is easily programmed, from provides a small form factor and low 800mV to 90% of V_{IN} with two profile at 3x3x1mm with excellent power dissipation capability on surface mount PCB's.

IMPORTANT: For the most current data, consult MICROSEMI's website: http://www.microsemi.com

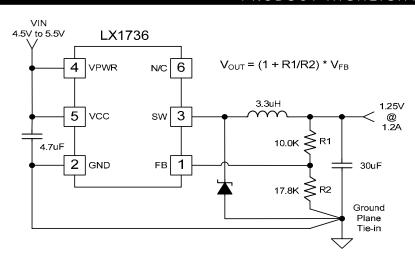
KEY FEATURES

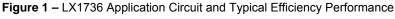
- Few External Components
- 800mv Internal Reference
- Tight Regulation over Line, Load and Temperature
- 4.5V to 5.5V Input Range
- Internal Soft Start Controls Inrush Current
- High Efficiency
- Low Quiescent Current, 600µA
- Fully Fault Protected
- Thin MO-229, 6-Pin Package

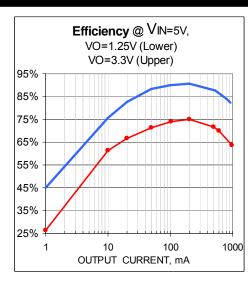
APPLICATIONS

- Point of Load Regulation
- DSP, ASIC and Core Voltage Supplies
- Hard Disk Drives
- Set Top Boxes
- RoHS compliant product

PRODUCT HIGHLIGHT









Package Marking 3049 XXXX **MSC**

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ABSOLUTE MAXIMUM RATINGS

Input Voltage (VCC or VPWR)	0.3V to 7.0V
SW to GND	$0.3V \text{ to } (V_{IN} + 0.3V)$
VFB to GND	0.3V to +2V
SW Peak Current	Internally Limited
Junction Operating Temperature Range	0°C to +125°C
Storage Temperature Range, TA	65°C to 150°C
Maximum Junction Temperature	150°C
Package Peak Temp. for Solder Reflow (40 seconds max. exposure)	

Note: Exceeding these ratings could cause damage to the device. All voltages are with respect to Ground. Currents are positive into, negative out of specified terminal.

PACKAGE PIN OUT FB O SW LD PACKAGE (Top View)

RoHS / Pb-free 100% matte Tin Pin Finish

THERMAL DATA

Plastic MLP 3x3mm MO-229, 6-Pin

THERMAL RESISTANCE-JUNCTION TO CASE, θ_{JC}	4°C/W		
THERMAL RESISTANCE-JUNCTION TO AMBIENT, θ_{JA}	25 to 50°C/W		

Junction Temperature Calculation: $T_J = T_A + (P_D \times \theta_{JA})$.

The θ_{JA} numbers are guidelines for the thermal performance of the device/pc-board system. All of the above assume no ambient airflow.

FUNCTIONAL PIN DESCRIPTION									
Name	lame Pin # Description								
VCC	5	Unregulated supply voltage input, ranging from +4V to 6.0V for internal analog control circuitry.							
VPWR	PWR 4 Unregulated supply voltage input (+4V to 6.0V), high current path, supplies PMOSFET Drain of PWM switch.								
FB	Feedback input for setting programming output voltage.								
GND 2 Circuit ground for IC analog circuitry and high frequency gate drive bias, exposed pad area on bottom of package may be connected to ground or left floating.									
SW	3	Inductor and commutation diode connection point. Connects to internal PMOSFET Source of PWM Switch output.							

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	LX1736			Unit
Falalletel	Symbol	Min	Тур	Max	Offic
Input Operating Voltage Range	V_{IN}	4.5		5.5	V
Continuous Output Current Range	lout	0		0.9	Α
Output Voltage Range	V _{OUT}	0.8		80% of V _{IN}	V
Operating Junction Temperature	TJ	0		125	°C



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ELECTRICAL CHARACTERISTICS

Specifications are guaranteed over the junction temperature range of: $0^{\circ}\text{C} < \text{T} < 125^{\circ}\text{C}$ for VIN = 4.5V to 5.5V (unless noted otherwise), not all of these parameters are production tested but are assured by design, characterization and correlation with statistical process controls.. Typical values are at TA=23°C.

Parameter	Symbol	Test Conditions	LX1736		1	Units	
- arameter	Cy201	1001 001101110110	Min	Тур	Max	• • • • • • • • • • • • • • • • • • •	
Feedback Threshold	V_{FBT}	4.0V < VIN < 6.0V	772	800	828	mV	
Feedback Input Current	I _{FB-IN}	V _{FB} = V _{FBT} + 10mV			75	nA	
PWM Frequency	F _{OP-PWM}	PWM Mode	800		1450	Khz	
PFM Mode Transition	IO-PFM	PFM mode		80		mA	
Minimum DC Output Current	I _{OUT}		0			mA	
Maximum DC Output Current	I _{OUTMAX}	T _J ≤ 70°C			1.25 or 0.7/duty cycle whichever is less	А	
Maximum Duty Cycle	D _{MAX}	I _{SW} = I _{OUT} max	80			%	
Closed Loop Load Regulation	V _{OUT Load}	10mA <i<sub>OUT<i<sub>OUT MAX</i<sub></i<sub>	-0.5		0.5	%V _{OUT}	
Efficiency	n	V _{IN} =5V, V _{OUT} ≥1.1V, I _{OUT} = 10mA	55			%	
Efficiency	η	V _{IN} =5V, V _{OUT} >1.1V, I _{OUT} ≥ 150mA	70			%	
Quiescent Current	IQ	I_Q $V_{FB} = V_{FBT} + 10 \text{mV}$		600	900	μΑ	
P-Channel Switch ON Resistance	$I R_{DO(ON)} I I_{OM} = I I U A$			0.375		Ω	
P-Channel Switch Current Limit	I _{SW CL}	Peak Current at Switch Pin (Not DC Current)	1.1			А	
		T _J ≤ 70°C	1.4				
P-Channel Switch Leakage	I _{SW LKG}	$V_{FB} = V_{FBT} + 10mV$			5	μA	
Soft Start, VOUT Slew Rate	V _{O-SR}	Initial Power On or After a Short Circuit, $C_{OUT} = 20 \mu F$		21	50	V/ms	
Thermal Shutdown	T _{SD}	(Silicon Temperature)	135	150		°C	
DC Average In-Rush Current at VCC and VPWR (summed)	I _{INRUSH}	V_{IN} ramping from 0V to 5V having a slew rate of 0.1V/S min to 0.5V/uS max and C_{OUT} = 20 μ F			550	mA	
Output Voltage Overshoot (From either removal of a short circuit condition from V _{OUT} or applied power during start up)		Applied power V _{IN} ramp rate of 0.1V/S min to 0.5V/uS max			5	%	
Output Voltage Response to Dynamic Load Change			-5		5	%	
Circuit Output Capacitance	C _{OUT}	Closed Loop stability	20			μF	



Cout

Ground

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Vout INDUCTOR DIODE Cout Cout Vin Vpwr Sw

APPLICATION SUPPORT

PCB Layout Considerations

- 1- Maintain separate traces leading from the decoupling capacitor, C_{IN}, to the supply input pins of the IC for VCC and VPWR. This ensures that the noise and voltage drops associated with the high dl/dt pulses from the PWM switching are minimized for the internal control circuitry of the IC.
- 2- Diode ground should return to C_{OUT} ground with minimum physical distance before joining the IC Ground connection.

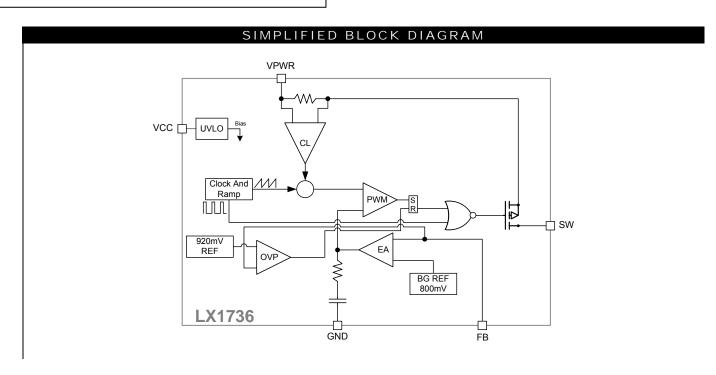
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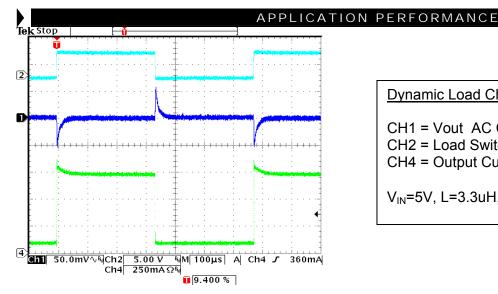
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3- Feed back resistor return path to ground should be located closely to the IC Pin 2 to avoid V_{OUT} offsets induced by ground drops and noise.



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Dynamic Load Change Response

CH1 = Vout AC Coupled

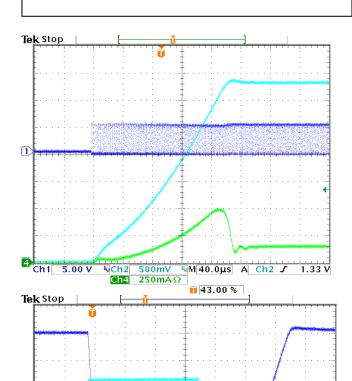
CH2 = Load Switch

CH4 = Output Current, 100mA to 750mA

 V_{IN} =5V, L=3.3uH, C_{OUT} = 20uF



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Ghi 200mV % Ch2 2.00 V % M 40.0 μs A Ch4 \ 2.42 A Ch4 1.00 A Ω

II 19.20 %

Start-up Inrush Current Control

CH1 = SW Pin

CH2 = Vout @ 3.32V

CH4 = Input Current

V_{IN}=5V, No Output load, C_{OUT} = 20uF

VOUT Response to Short Circuit Removal

CH1 = Vout programmed at 1.2V

CH2 = Short CKT Duration

CH4 = Output Current

 $C_{OUT} = 20uF$

2

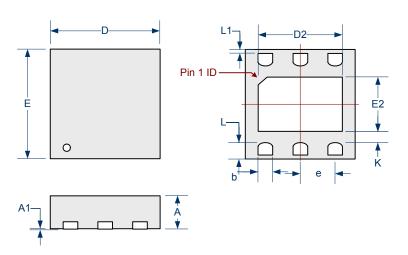
4



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PACKAGE DIMENSIONS

MO-229 6-Pin Plastic 3 x 3 x .9 mm



	MILLIMETERS		ERS INCHES		
Dim	MIN	MAX	MIN	MAX	
Α	0.80	1.00	0.031	0.039	
A1	0.00	0.05	0.000	0.002	
K	0.20 MIN		0.008 MIN		
е	0.95 BSC		0.037 BSC		
L	0.30	0.50	0.012	0.020	
b	0.30	0.45	0.012	0.018	
D2	1.90	2.40	0.075	0.094	
E2	1.15	1.65	0.045	0.065	
D	3.00 BSC		0.118 BSC		
Е	3.00 BSC		0.118 BSC		
L1	0.00	0.15	0.000	0.006	

Note:

- Dimensions do not include mold flash or protrusions; these shall not exceed 0.155mm(.006") on any side. Lead dimension shall not include solder coverage.
- Exposed heatsink pad on bottom may be left floating or connected to ground.

NOTES

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